## 2SD1979G

## Silicon NPN epitaxial planar type

For low frequency amplification

For muting

For DC-DC converter

#### ■ Features

- Low ON resistance Ron
- High forward current transfer ratio h<sub>FE</sub>
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

## ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	$V_{CBO}$	50	V	
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	20	V	
Emitter-base voltage (Collector open)	$V_{EBO}$	25	V	
Collector current	$I_{C}$	300	mA	
Peak collector current	I <sub>CP</sub>	500	mA	
Collector power dissipation	$P_{\rm C}$	150	mW	
Junction temperature	$T_{j}$	150	°C√0	
Storage temperature	T <sub>stg</sub>	-55 to +150	°C	

### ■ Package

- Code
- SMini3-F2
- Marking Symbol: 3W
- Pin Name
  - 1: Base
  - 2: Emitter
  - 3: Collector

### ■ Electrical Characteristics T<sub>a</sub> = 25°C ± 3°C

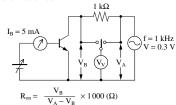
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	$V_{CEO}$	$I_C = 1 \text{ mA}, I_B = 0$	20	0		V
Base-emitter voltage	$V_{BE}$	$V_{CE} = 2 \text{ V}, I_{C} = 4 \text{ mA}$	1.00	0.6		V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 50 \text{ V}, I_{E} = 0$			1	μΑ
Emitter-base cutoff current (Collector open)	$I_{EBO}$	$V_{EB} = 25 \text{ V}, I_C = 0$			1	μΑ
Forward current transfer ratio *1	h <sub>FE</sub>	$V_{CE} = 2 \text{ V}, I_{C} = 4 \text{ mA}$	500		2500	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 30 \text{ mA}, I_B = 3 \text{ mA}$			0.1	V
Transition frequency	$f_T$	$V_{CB} = 6 \text{ V}, I_E = -4 \text{ mA}, f = 200 \text{ MHz}$		80		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		4.5		pF
(Common base, input open circuited)		Oleo I.				
ON resistance *2	R <sub>on</sub>			1		Ω

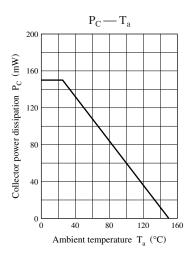
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

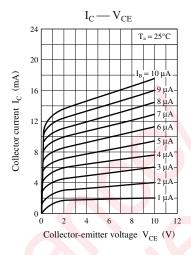
#### 2. \*1: Rank classification

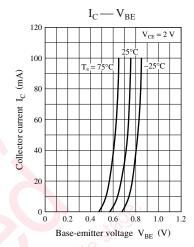
Rank	S	Т
h <sub>FE</sub>	500 to 1500	800 to 2500

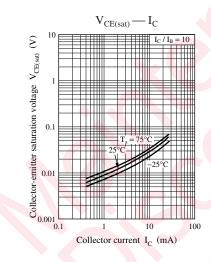
\*2: Ron Measuremet circuit

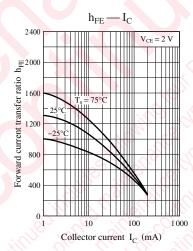


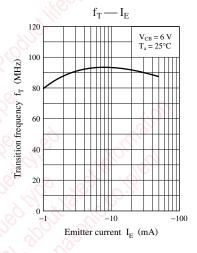


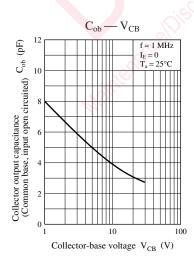




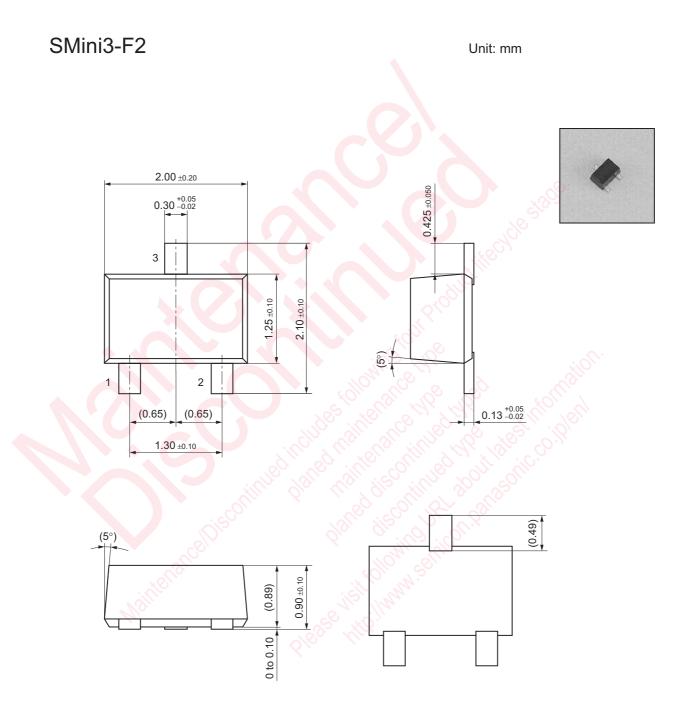








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